

## 2STF1340

### Low voltage fast-switching NPN power bipolar transistor

**Preliminary Data** 

#### **General features**

- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed
- Miniature SOT-89 plastic package for surface mounting circuits
- In compliance with the 2002/93/EC European Directive

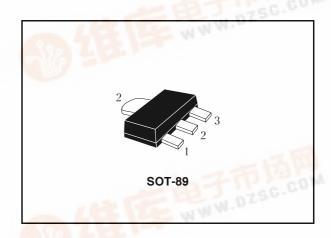


The device in a NPN transistor manufactured using new "PB-HCD" (Power Bipolar High Current Density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

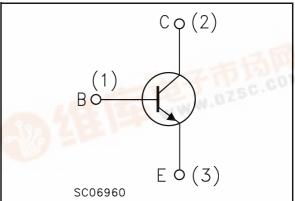
The complementary PNP is the 2STF2340.

## **Applications**

- LED
- Motherboard & hard disk drive
- Mobile equipment
- Battery charger
- Voltage regulation



### Internal schematic diagram



### **Order codes**

Part Number	Marking	Pack <mark>age</mark>	Packing
2STF1340	1340	SOT-89	Tape & reel
	理世	ZSC.COM	

Rev 1

## **Contents**

1	Electrical ratings	3
2	Electrical characteristics	4
3	Package mechanical data	5
4	Revision history	7

**577** 

2STF1340 Electrical ratings

# 1 Electrical ratings

Table 1. Absolute maximum rating

Symbol	Parameter	Value	Unit
V <sub>CES</sub>	Collector-emitter voltage (V <sub>CE</sub> = 0)	40	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	40	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	5	V
I <sub>C</sub>	Collector current	3	Α
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5ms)	6	Α
P <sub>tot</sub>	Total dissipation at T <sub>amb</sub> = 25°C	1.4	W
T <sub>stg</sub>	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 2. Thermal data

Symb	Parameter	Value	Unit
R <sub>thj-am</sub>	Thermal resistance junction-amb max	89.3	°C/W

(1) Device mounted on PCB area of  $1\,\mathrm{cm}^2$ 

Electrical characteristics 2STF1340

## 2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$ 

Table 3. Electrical characteristics

Symbol	Parameter	Test C	Min.	Тур.	Max.	Unit	
ІСВО	Collector cut-off current (I <sub>E</sub> =0)	V <sub>CB</sub> = 40V				0.1	μΑ
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> =0)	V <sub>EB</sub> = 5V				0.1	μА
V <sub>(BR)CBO</sub>	Collector-emitter breakdown voltage (I <sub>E</sub> = 0)	Ι <sub>C</sub> = 100μΑ		40			V
V <sub>(BR)CEO</sub> (2)	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 10mA		40			V
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 100μA		5			V
V <sub>CE(sat)</sub> (2)	Collector-emitter	I <sub>C</sub> = 2A	I <sub>B</sub> = 100mA		0.2		V
	saturation voltage	$I_C = 3A$	$I_B = 150 \text{mA}$		0.3		V
V <sub>BE(sat)</sub> (2)	Base-emitter saturation voltage	I <sub>C</sub> = 2A	I <sub>B</sub> = 100mA		0.9	1.25	V
		I <sub>C</sub> = 0.1A	V <sub>CE</sub> = 2V		280		
h <sub>FE</sub> <sup>(2)</sup>	DC current gain	$I_C = 1A$	$V_{CE} = 2V$		250		
		$I_C = 3A$	$V_{CE} = 2V$		200		
f <sub>T</sub>	Transition frequency	I <sub>C</sub> = 0.1A f = 100MHz	V <sub>CE</sub> = 5V	100			MHz
C <sub>CBO</sub>	Collector-base capacitance	I <sub>E</sub> = 0 f = 1MHz	V <sub>CB</sub> = 10V		tbd		pF
t <sub>on</sub>	Resistive load Turn-on time Turn-off time	$I_C = 1.5A$ $I_{B1} = -I_{B2} = 1$			tbd tbd		ns ns

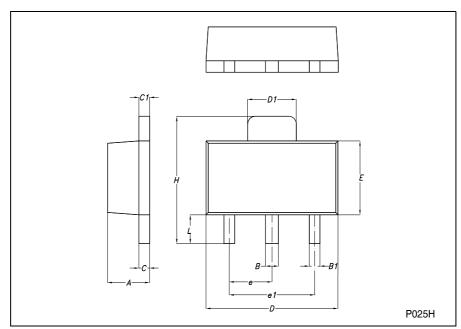
Note (2) Pulsed duration = 300  $\mu$ s, duty cycle  $\leq$ 1.5%

## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

### **SOT-89 MECHANICAL DATA**

DIM.	mm			mils			
DIWI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α	1.4		1.6	55.1		63.0	
В	0.44		0.56	17.3		22.0	
B1	0.36		0.48	14.2		18.9	
С	0.35		0.44	13.8		17.3	
C1	0.35		0.44	13.8		17.3	
D	4.4		4.6	173.2		181.1	
D1	1.62		1.83	63.8		72.0	
Е	2.29		2.6	90.2		102.4	
е	1.42		1.57	55.9		61.8	
e1	2.92		3.07	115.0		120.9	
Н	3.94		4.25	155.1		167.3	
L	0.89		1.2	35.0		47.2	



2STF1340 Revision history

# 4 Revision history

Table 4. Revision history

Date	Revision	Changes
20-Oct-2006	1	Initial release.

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4